
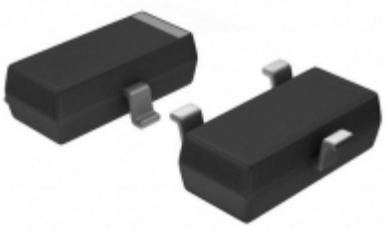
	<p>SI2316BDS-T1-E3</p>
	<p>Hersteller-Teilenummer: SI2316BDS-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 4.5A SOT-23</p> <p>Datenblätter:  SI2316BDS-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 83278 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI2316BDS-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 30V 4.5A SOT-23
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	83278 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-236-3, SC-59, SOT-23-3
Supplier Device-Gehäuse	SOT-23-3 (TO-236)
Verlustleistung (max)	1.25W (Ta), 1.66W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	4.5A (Tc)
Rds On (Max) @ Id, Vgs	50 mOhm @ 3.9A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	9.6nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	350pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)

SI2316BDS-T1-E3 ist neu im Original, Suche SI2316BDS-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI2316BDS-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI2316BDS-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI2316-DS VISHAY SI2316-DS VISHAY</p>	 <p>SI2316DS 89K SI2316DS 89K</p>	 <p>SI2315DS-TEZ VISHAY SI2315DS-TEZ VISHAY</p>	 <p>SI2316BDS-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 4.5A SOT23-3</p>
 <p>SI2316BDS-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 4.5A SOT-23</p>	 <p>SI2316BDS VISHAY VISHAY SOD23</p>	 <p>SI2316BDS-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 4.5A SOT23-3</p>	 <p>SI2316DS-T1-E3 Vishay / Siliconix MOSFET N-CH 30V 2.9A SOT23-3</p>

heiße Teile

Mehr

SI2312DS-T1	SI2312DS-T1-E3	SI2312DS-T1-GE3	SI2313DS	SI2313DS-T1-E3
SI2313DS-T1-GE3	SI2314DS	SI2314DS-T1-E3	SI2314DS-T1-GE3	SI2314EDS
SI2314EDS-T1-E3	SI2314EDS-T1-E3	SI2314EDS-T1-GE3	SI2314EDS-T1-GE3	SI2315BDS
SI2315BDS-T1-E3	SI2315BDS-T1-E3	SI2315BDS-T1-GE3	SI2315BDS-T1-GE3	SI2315DS
SI2315DS-T1	SI2315DS-T1-E3	SI2315DS-T1-GE3	SI2316-DS	SI2316BDS-T1-E3
SI2316BDS-T1-GE3	SI2316BDS-T1-GE3	SI2316DS	SI2316DS-T1-E3	SI2316DS-T1-E3
SI2316DS-T1-GE3	SI2316DS-T1-GE3	SI2317DS	SI2317DS-T1-E3	SI2318ADS-T1-GE3
SI2318BDS-T1-E3	SI2318BDS-T1-GE3	SI2318CDS-T1-E3	SI2318CDS-T1-GE3	SI2318CDS-T1-GE3
SI2318DS	SI2318DS-T1-E3	SI2318DS-T1-E3	SI2318DS-T1-GE3	SI2318DS-T1-GE3
SI2319ADS-T1-GE3	SI2319C95TF	SI2319CDS-T1-E3	SI2319CDS-T1-GE3	SI2319CDS-T1-GE3

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